

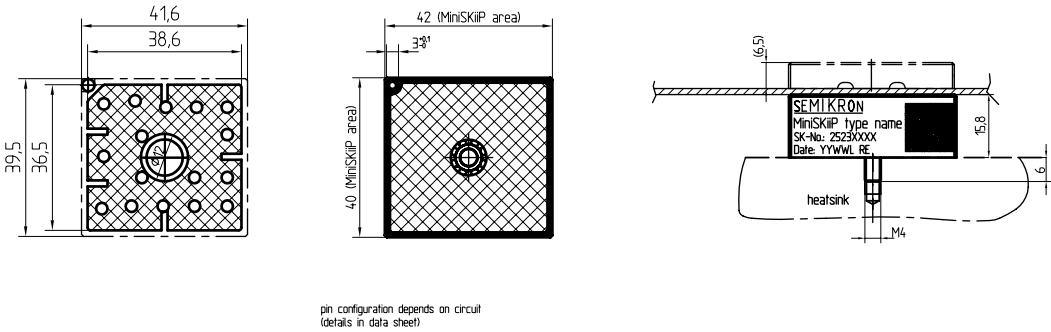
SiC Modules / Full SiC / MiniSKiiP

Type						
	V_{DS}	I_D @ T_C = 25°C	R_{DS(on)} @ T_J = 25°C typ.	R_{th(j-a)}	Case	Circuit
	V	A	mΩ	K/W		
1200V - SiC MOSFET						
SKiiP 13ACM12V17 ¹⁾	1200	25	80	1.5	II 1	
SKiiP 13ACM12V18 ¹⁾	1200	25	80	1.5	II 1	
SKiiP 26ACM12V17 ¹⁾	1200	72	23	0.6	II 2	

Footnotes: 1) Sample status

Cases

MiniSKiiP II 1

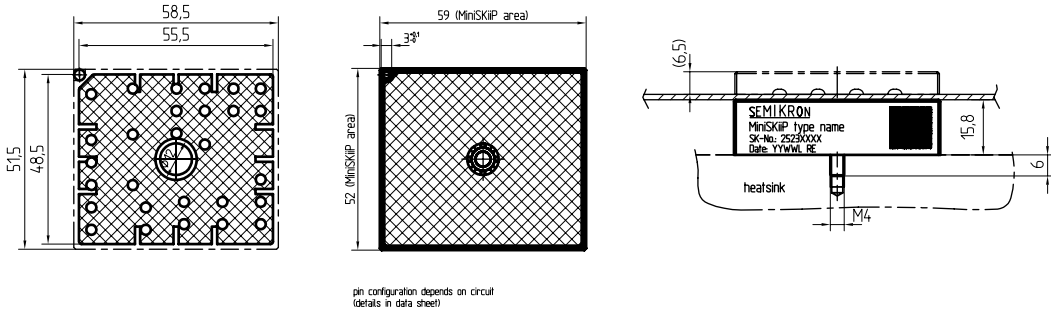


Dimensions in mm

SiC Modules / Full SiC / MiniSKiiP

Cases

MiniSKiiP II 2



Dimensions in mm